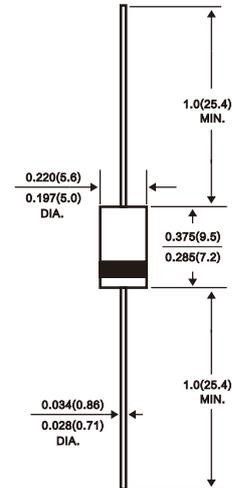


Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Epoxy: UL 94V-O rate flame retardant

DO-27(DO-201AD)

Dimensions in inches and (millimeters)
Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	HER 501	HER 502	HER 503	HER 504	HER 505	HER 506	HER 507	HER 508	Unit	
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V	
Working Peak Reverse Voltage	V_{RWM}										
DC Blocking Voltage	V_R										
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V	
Average Rectified Output Current (Note 1)	I_O	5.0								A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150								A	
Forward Voltage @ $I_F = 5.0A$	V_{FM}	1.0			1.3		1.7			V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	I_{RM}	10 100								μA	
Reverse Recovery Time (Note 2)	t_{rr}	50					75				nS
Typical Junction Capacitance (Note 3)	C_j	75					50				pF
Operating Temperature Range	T_j	-65 to +125								$^\circ\text{C}$	
Storage Temperature Range	T_{STG}	-65 to +150								$^\circ\text{C}$	

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
2. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $IRR = 0.25A$. See figure 5.
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

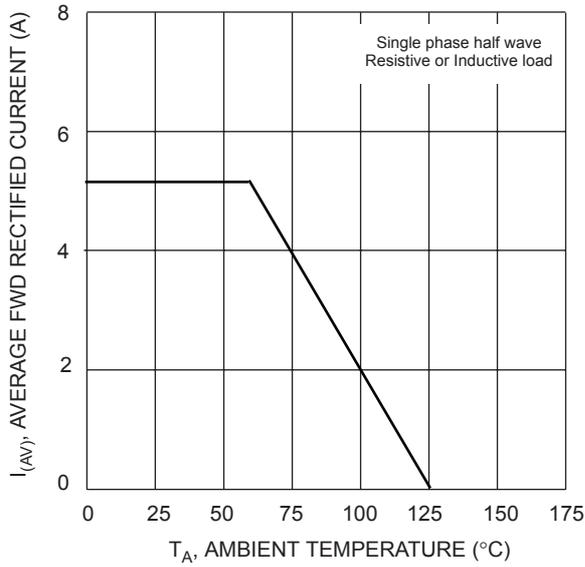


Fig. 1 Forward Current Derating Curve

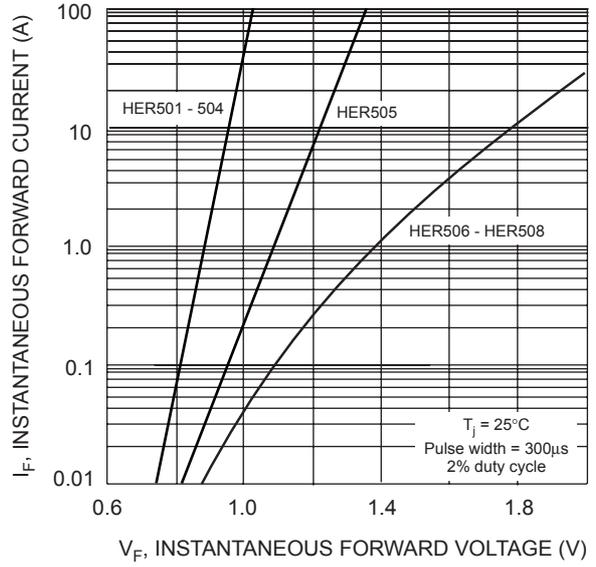


Fig. 2 Typical Forward Characteristics

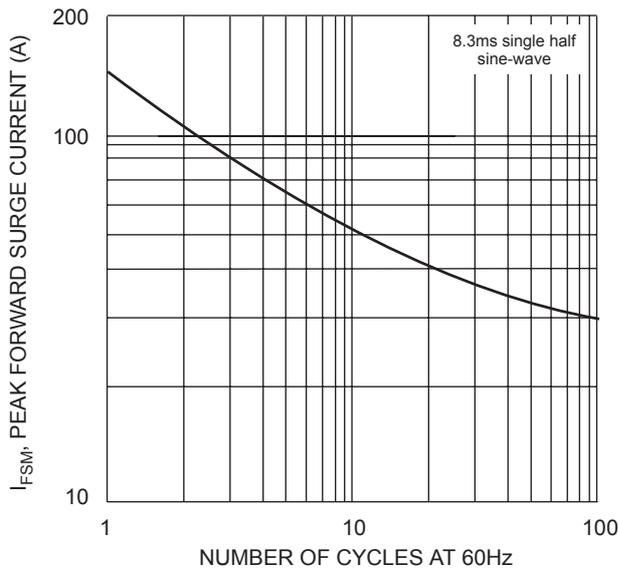


Fig. 3 Peak Forward Surge Current

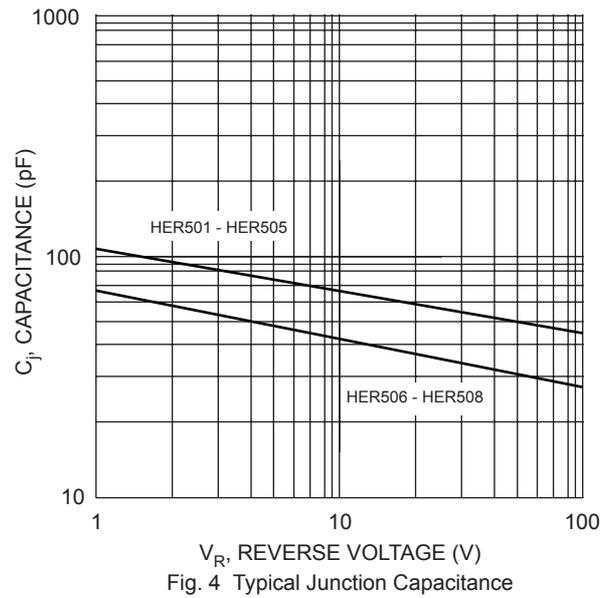
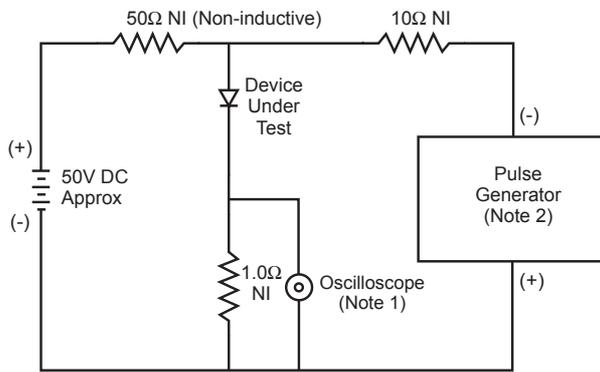


Fig. 4 Typical Junction Capacitance



Notes:

2. Rise Time = 10ns max. Input Impedance = 50Ω.

1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.

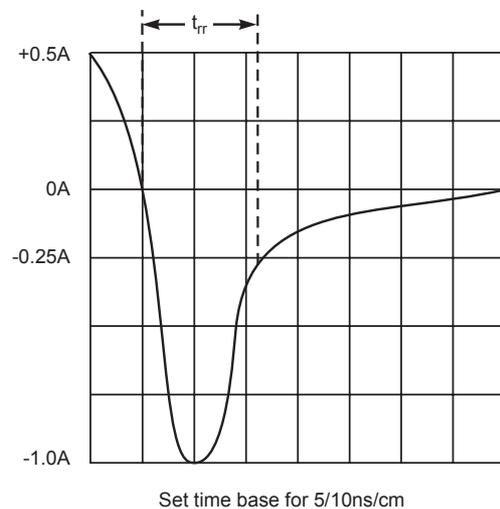


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit